

Si52254/Si52258 Data Sheet

4/8-Output PCIe Gen1/2/3/4/5 Clock Generator

The Si52258/54 are the industry's highest performance and lowest power automotive grade PCI Express clock generators for PCIe Gen1/2/3/4/5 common clock and/or SRIS applications. The Si52258 and Si52254 source eight and four 100 MHz PCIe differential clock outputs, respectively. All clock outputs are compliant to PCIe Gen1/2/3/4/5 common clock and separate reference clock architecture specifications.

Hardware control pins are available for enabling and disabling the outputs, as well as spread spectrum enable/disable for EMI reduction.

For more information about PCI Express, Silicon Labs' complete PCIe portfolio, application notes, and design tools, including the Silicon Labs PCIe Clock Jitter Tool for PCI Express compliance, please visit the Silicon Labs PCI Express Learning Center.

Applications:

- Infotainment
- ADAS ECU

- Radar Sensors
- · LiDar Sensors

KEY FEATURES

- 8/4-outputs with internal termination
- PCIe Gen 1/2/3/4/5 compliant
- Automotive grade 2: –40 to +105 °C
- Internal 100 Ω or 85 Ω line matching
- Excellent jitter performance
 - 0.05 ps RMS (Gen3/4)
 - 0.025 ps RMS (Gen5)
- Triangular spread spectrum for EMI reduction, down spread 0.25% or 0.5%
- Individual hardware control pins for Output Enable, Spread Spectrum Enable
- Enable and Frequency Select
- · 25 MHz crystal input or clock input
- 1.8–3.3 V power supply
- Pb-free, RoHS-6 compliant

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1. Features List

- · 8/4-100 MHz HCSL outputs with internal termination
- PCIe Gen1/2/3/4/5 compliant
- Automotive grade 2: -40 to +105 °C
- Internal 100 Ω or 85 Ω line matching
- Excellent jitter performance
 - 0.05 ps RMS (Gen3/4)
 - 0.025 ps RMS (Gen5)
- Triangular spread spectrum for EMI reduction, down spread 0.25% or 0.5%
- · Individual hardware control pins for Impedance Select, Output Enable, and Spread Spectrum Enable
- Loss of Signal (LOS) output pin
- · 25 MHz crystal input or clock input
- 1.8–3.3 V power supply
- Pb-free, RoHS-6 compliant

2. Ordering Guide

Number of Outputs	Part Number	Package Type	Temperature
8	Si52258A-D01AM	40-QFN	Automotive, -40 to 105 °C
	Si52258A-D01AMR	40-QFN – Tape and Reel	Automotive, -40 to 105 °C
4	Si52254A-D01AM	32-QFN	Automotive, -40 to 105 °C
	Si52254A-D01AMR	32-QFN – Tape and Reel	Automotive, -40 to 105 °C

3. Functional Description

3.1 Functional Block Diagram



Figure 3.1. Si5225x Block Diagram

3.2 Crystal Recommendations

The Si52258/4 operates from a parallel resonance 25 MHz crystal. Crystal operation requires external loading capacitors to match crystal capacitive loading requirements. Si52258/4 XA/XB inputs present 2.5 pf of stray capacitance.

3.3 HCSL Differential Output Terminations

Termination for HCSL Outputs

The Si52254/8 HCSL drivers feature integrated termination resistors to simplify interfacing to an HCSL receiver. The HCSL driver supports both 100 Ω and 85 Ω transmission line options, and can be selected using the IMP_SEL hardware input pin.



Figure 3.2. HCSL Internal Termination Mode

3.4 Output Enable/Disable

An output enable pin provides a convenient method of disabling or enabling the output drivers. When the output enable pin is held high, all designated outputs will be disabled. When held low, the designated outputs will be enabled.

3.5 Spread Spectrum

To help reduce electromagnetic interference (EMI), the Si52254/8 supports spread spectrum modulation. Spread spectrum can be enabled by the hardware input pin.

3.6 Loss of Signal (LOS)

The LOS indicator is used to check for the presence of an input reference source (crystal). LOS will assert when the reference source frequency drops below approximately 10 MHz.

In the event that a reference source is not present, the associated LOS pin will assume a logic low (LOS = 0) state. When a reference source is present, the LOS pin will assume a logic high (LOS = 1) state.

The LOS output is active low, open drain, and requires an external pull-up resistor of 1 k Ω or greater.

4. Power Supply Filtering Recommendations

The Si52258/4 features internal LDOs on each power supply pin, providing excellent power supply noise rejection. As a guideline, each power supply pin should use a parallel combination of a 1 μ f and a 0.1 μ F bypass capacitor placed as close to the supply pin as possible.

5. Electrical Specifications

Table 5.1. Recommended Operating Conditions

 $(V_{DD} = V_{DDA} = V_{DD_{DIG}} = V_{DD_{XTAL}} = 1.8 V \text{ to } 3.3 V + 5\% / -5\%, V_{DDO} = 1.8 V \pm 5\%, 2.5 V \pm 5\%, \text{ or } 3.3 V \pm 5\%, T_A = -40 \text{ to } 105 \text{ °C})$

Parameter	Symbol	Test Condition	Min	Тур	Мах	Units
Ambient Temperature	T _A		-40	25	105	°C
Junction Temperature	TJ _{MAX}		—	_	125	°C
Core Supply Voltage ^{1, 2}	V _{DDA} , V _{DD_DIG} , V _{DD_xtal}		1.71	_	3.46	V
Output Driver Supply Voltage	V _{DDO}		1.71	_	3.46	V

Note:

1. All minimum and maximum specifications are guaranteed and apply across the recommended operating conditions. Typical values apply at nominal supply voltages and an operating temperature of 25 °C unless otherwise noted.

2. All core voltages (VDD_DIG, VDDA, VDD_XTAL) must be connected to the same voltage.

Table 5.2. DC Characteristics

 $(V_{DD} = V_{DDA} = V_{DD} DIG = V_{DD} XTAL = 1.8 V to 3.3 V +5\% -5\%, V_{DDO} = 1.8 V \pm 5\%, 2.5 V \pm 5\%, or 3.3 V \pm 5\%, T_A = -40 to 105 °C)$

Parameter	Symbol	Test Condition		Min	Тур	Мах	Units
Core Supply Current	I _{DD}			—	26	40	mA
Output Buffer Supply Cur- rent	I _{DDOx}	HCSL Output ¹ @ 100 MHz		_	20	22	mA
Tatal Davis Disationation?	р	40-pin			550	750	mW
Total Power Dissipation ²	Pd	32-pin		_	300	445	mW
Notes:							
1. Differential outputs terminated into a 100 Ω load at 3.3 V.							

2. Total power dissipation calculated with all 100 MHz HCSL running at 3.3 V.

Table 5.3. External Crystal Input Specification

 $(V_{DD} = V_{DDA} = V_{DD} DIG = V_{DD} XTAL = 1.8 V to 3.3 V +5\% -5\%, V_{DDO} = 1.8 V \pm 5\%, 2.5 V \pm 5\%, or 3.3 V \pm 5\%, T_A = -40 to 105 °C)$

Parameter	Symbol	Test Condition	Min	Тур	Max	Units
Crystal Frequency	F _{xtal}			25		MHz
Crystal Drive Level	dL		_	_	250	μW
Input Capacitance	C _{IN}		_	2.5		pF
Input Voltage	V _{XIN}		-0.3	_	1.3	V

Table 5.4. Differential Clock Output Specifications

Parameter	Symbol	Test Condition		Min	Тур	Max	Units
Output Frequency	fout				100		MHz
Duty Cycle	DC			48	_	52	%
Output-Output Skew	Т _{SK}			—	—	80	ps
Output Voltage Swing	V _{SEPP}	HCSL		0.7	0.8	0.9	V _{PP}
Common Mode Voltage	V _{CM}	HCSL		0.35	0.4	0.45	V
HCSL Edge Rate	Edgr	Notes 1,	2, 3	1	_	4.5	V/ns
HCSL Delta Tr	D _{tr}	Notes 2,	4, 5	—	_	155	ps
HCSL Delta Tf	D _{tf}	Notes 2,	4, 5	_		155	ps
HCSL Vcross Abs	V _{xa}	Notes 6, 7	7, 2, 4	250		550	mV
HCSL Delta Vcross	D _{vcrs}	Notes 2, 4, 8		_	_	140	mV
HCSL Vovs	V _{ovs}	Notes 2, 4, 9		_	_	V _{HIGH} +300	mV
HCSL Vuds	V _{uds}	Notes 2, 4, 10		_	_	V _{LOW} -300	mV
HCSL Vrng	V _{rng}	Notes 2, 4		V _{HIGH} -200	_	V _{LOW} +200	mV
Rise and Fall Times (20% to 80%)	t _R /t _F	HCSL		_	_	420	ps

(V_{DD} = V_{DDA} = V_{DD DIG} = V_{DD XTAL} = 1.8 V to 3.3 V +5%/-5%, V_{DDO} = 1.8 V ±5%, 2.5 V ±5%, or 3.3 V ±5%, T_A = -40 to 105 °C)

Notes:

1. Measure taken from differential waveform on a component test board. The edge (slew) rate is measured from –150 mV to +150 mV on the differential waveform. Scope is set to average because the scope sample clock is making most of the dynamic wiggles along the clock edge Only valid for Rising clock and Falling Clock#. Signal must be monotonic through the Vol to Voh region for Trise and Tfall.

- 2. Applies to a 2 pf load with both internal or external 50 Ω or 42.5 Ω Rp.
- 3. Measurement taken from differential waveform.
- 4. Measurement taken from Single Ended waveform.
- 5. Measured with oscilloscope, averaging off, using min max statistics. Variation is the delta between min and max.



- 6. Measured at crossing point where the instantaneous voltage value of the rising edge of CLK equals the falling edge of CLK#.
- 7. This measurement refers to the total variation from the lowest crossing point to the highest, regardless of which edge is crossing.
- 8. ΔVcross is defined as the total variation of all crossing voltages of Rising CLOCK and Falling CLOCK#. This is the maximum allowed variance in Vcross for any particular system.
- 9. Overshoot is defined as the absolute value of the maximum voltage.
- 10. Undershoot is defined as the absolute value of the minimum voltage.

Table 5.5. Performance Characteristics

 $(V_{DD} = V_{DDA} = V_{DD_{DIG}} = V_{DD_{XTAL}} = 1.8 \text{ V to } 3.3 \text{ V } +5\% -5\%, V_{DDO} = 1.8 \text{ V } \pm5\%, 2.5 \text{ V } \pm5\%, \text{ or } 3.3 \text{ V } \pm5\%, \text{ T}_{A} = -40 \text{ to } 105 \text{ }^{\circ}\text{C})$

Parameter	Symbol	Test Condition	Min	Тур	Мах	Units
Power Ramp	t _{VDD}	0 V to V _{DDmin}	0.1	_	10	ms
Clock Stabilization from Power-up	t _{STABLE}	Time for clock outputs to appear after POR	_	15	25	ms
0.5% Down Spread Frequency Deviation	SSDEV		0.4	0.45	0.5	%
Spread Spectrum Modulation Rate	SSDEV		30	31.5	33	kHz
Notes: 1. Default value is ~31.5 kHz.						

Table 5.6. PCI-Express Clock Outputs (100 MHz HCSL)

$(V_{DD} = V_{DDA} = V_{DD_DIG} = V_{DD_XTAL} = 1.8 \text{ V to } 3.3 \text{ V } +5\% -5\%, V_{DDO} = 1.8 \text{ V } \pm5\%, 2.5 \text{ V } \pm5\%, \text{ or } 3.3 \text{ V } \pm5\%, T_A = -40 \text{ to } 105 \text{ °C})$

Parameter	Test Condition	SSC On/Off	Тур	Мах	Units	
	Includes PLL BW 1.5–22 MHz,	Off	11	19	ps RMS	
PCle Gen 1.1	Peaking = 3 dB, Td = 10 ns,	2		30	5140	
	Ftrk = 1.5 MHz with BER = 1E-12 1	On	22		ps RMS	
	Includes PLL BW 5MHz and 8–16 MHz,	Off	0.02	0.026	ps RMS	
	Jitter Peaking = 0.01–1 dB and 3 dB,	_				
	Td = 12 ns, Low Band, F < 1.5 MHz ¹	On	0.12	0.21	ps RMS	
PCIe Gen 2.1	Includes PLL BW 5 MHz and 8–16 MHz,	Off	0.2	0.31	ps RMS	
	Jitter Peaking = 0.01–1 dB and 3 dB,					
	Td = 12 ns, High Band, 1.5 MHz < F < Nyquist ¹	On	0.8	1.35	ps RMS	
	Includes PLL BW 2–4 MHz and 5 MHz, Peaking =	Off	0.06	0.1	ps RMS	
PCIe Gen 3.0 Com- mon Clock	0.01–2 dB and 1 dB, Td = 12 ns, CDR = 10 MHz ^{1, 2}	On	0.26	0.38	ps RMS	
	Includes PLL BW 4 MHz					
PCIe Gen3.0 SRIS	Peaking = 2 dB and 1dB, Td = 12 ns	On	0.35	0.37	ps RMS	
	CDR = 10 MHz ^{1, 2}					
	Includes PLL BW 2–4 MHz and 5 MHz, Peaking =	Off	0.05	0.1	ps RMS	
PCIe Gen 4.0 Com- mon Clock	0.01–2 dB and 1dB, Td = 12 ns, CDR = 10 MHz ^{1, 2}	On	0.26	0.38	ps RMS	
	•					
	Includes PLL BW 4 MHz					
PCIe Gen4.0 SRIS	Peaking = 2 dB and 1 dB, Td = 12 ns	On	0.31	0.38	ps RMS	
	CDR = 10 MHz ^{1, 2}					
PCle Gen5.0 Com-		Off	0.025	0.04	ps RMS	
mon Clock		On	0.1	0.15	ps RMS	
PCIe Gen5.0 SRIS		On	0.08	0.1	ps RMS	
Note:		1	1	1	1	

Note:

1. All output clocks 100 MHz HCSL format. Jitter data taken from Clock Jitter Tool v.1.3.

2. Excludes oscilloscope sampling noise.

Parameter	Symbol	Test Condition ¹	Value	Units
Si52258 — 40 QFN				
		Still Air	23.1	
Thermal Resistance, Junction to Ambient	θ _{JA}	Air Flow 1 m/s	17.5	
		Air Flow 2 m/s	16.5	00000
Thermal Resistance, Junction to Case	θ _{JC}		13.4	°C/W
Thermal Desistance, Junction to Deard	θ _{JB}		8.7	
Thermal Resistance, Junction to Board	Ψјв	Still Air	8.4	
Si52254 — 32 QFN			1	1
		Still Air	28.4	
Thermal Resistance, Junction to Ambient	θ _{JA}	Air Flow 1 m/s	24	
		Air Flow 2 m/s	23	
Thermal Resistance, Junction to Case	θ _{JC}		15.9	°C/W
The much Devictor on the other to Devel	θ _{JB}		11.5	
Thermal Resistance, Junction to Board	Ψјв	Still Air	11.2	-
Note: 1. Based on JEDEC standard 4-layer PCB.				

Table 5.7. Thermal Characteristics

Parameter	Symbol	Test Condition	Value	Units
Storage Temperature Range	T _{STG}		-55 to +150	°C
	V _{DD}		-0.5 to 3.8	V
DC Cumples Voltage	V _{DDA}		-0.5 to 3.8	V
DC Supply Voltage	VDD _{xtal}		-0.5 to 3.8	V
	V _{DDO}		-0.5 to 3.8	V
Input Voltage Range	VI	XIN/XOUT	-0.3 to 1.3	V
Latch-up Tolerance	LU		JESD78 Com	pliant
ESD Tolerance	НВМ	100 pF, 1.5 kΩ	2.0	kV
Junction Temperature	T _{JCT}		-55 to 125	°C
Soldering Temperature	T _{PEAK}		260	°C
Soldering Temperature Time at T _{PEAK}	T _P		20 to 40	sec

Table 5.8. Absolute Maximum Ratings^{1,2,3}

Notes:

1. Permanent device damage may occur if the absolute maximum ratings are exceeded. Functional operation should be restricted to the conditions as specified in the operational sections of this data sheet. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

2. For more packaging information, go to www.silabs.com/support/quality/pages/RoHSInformation.aspx.

3. The device is compliant with JEDEC J-STD-020.

6. Pin Descriptions

6.1 Si52258A-D01AM Pin Descriptions (40-QFN)



Figure 6.1. 40-QFN

Pin Number	Pin Name	Pin Type	Function
1	VDD_DIG	Ρ	Voltage supply for digital functions. Connect to 1.8–3.3 V. Part of internal core VDD voltage. Must be connected to same voltage as VDDA and VDD_XTAL. Refer to 4. Power Supply Filtering Recommendations for by-pass capacitor recommendations.
			Output enable pin for OUT1.
2	OEb_OUT0	I	Low = output enabled
			High = output disabled
			Output enable pin for OUT1.
3	OEb_OUT1	I	Low = output enabled
			High = output disabled
4	VDD_XTAL	Ρ	Voltage supply for crystal oscillator. Connect to 1.8–3.3 V. Part of internal core VDD voltage. Must be connected to same voltage as VDDA and VDD_DIG. Refer to 4. Power Supply Filtering Recommendations for bypass capacitor recommendations.
5	XA	I	Connect to 25 MHz input crystal. Refer to Section 5. Electrical Specifica-
6	ХВ	0	tions for recommended crystal specifications.
			Output enable pin for OUT2.
7	7 OEb_OUT2		Low = output enabled
			High = output disabled
			Output enable pin for OUT3.
8	OEb_OUT3	I	Low = output enabled
			High = output disabled
			Core Supply Voltage. Connect to 1.8–3.3 V.
9	VDDA	Р	Must be connected to same voltage as VDD_DIG and VDD_XTAL.
			Refer to 4. Power Supply Filtering Recommendations for bypass capacitor recommendations.
10	LOS	0	 The LOS status pin indicates whether the reference input has dropped below approximately 10 MHz. LOS is active low, open drain output and requires an external pull-up resistor of 1 to 10 kΩ for proper operation. If LOS is not required, this pin can be left unconnected. 0 = reference input has dropped below approx. 10 MHz 1 = reference input is present (>10 MHz)
11	GND	_	Connect this pin to ground.
11	GND		Connect this pin to ground.
12	OUTOb	0	Output Clock
		0	_
14	Ουτο	0	100 MHz HCSL output. Termination recommendations are provided in 3.3 HCSL Differential Output Terminations. Unused outputs should be left unconnected.

Table 6.1. Si52258A-D01AM Pin Descriptions (40-QFN)

Pin Number	Pin Name	Pin Type	Function
			Supply Voltage (1.8–3.3 V) for OUT0
15	VDDO0	Р	Leave VDDOx pins of unused output drivers unconnected. An alternate op- tion is to connect the VDDOx pin to a power supply and disable the output driver to minimize current consumption. Refer to 4. Power Supply Filtering Recommendations for bypass capacitor recommendations.
16	OUT1b	0	Output Clock
17	OUT1	0	100 MHz HCSL output. Termination recommendations are provided in 3.3 HCSL Differential Output Terminations. Unused outputs should be left unconnected.
			Supply Voltage (1.8–3.3 V) for OUT1
18	VDDO1	Р	Leave VDDOx pins of unused output drivers unconnected. An alternate op- tion is to connect the VDDOx pin to a power supply and disable the output driver to minimize current consumption. Refer to 4. Power Supply Filtering Recommendations for bypass capacitor recommendations.
			Impedance select pin for output drivers. IMP_SEL pin is sampled at power- up only.
19	IMP_SEL	l	Low = 100 Ω
			High = 85 Ω
			Spread spectrum enable pin.
20	SSC_EN	I	Low = spread OFF
			High = spread ON (-0.5%)
21	OUT2b	0	Output Clock
22	OUT2	Ο	100 MHz HCSL output. Termination recommendations are provided in 3.3 HCSL Differential Output Terminations. Unused outputs should be left unconnected.
23	OUT3b	0	Output Clock
24	OUT3	0	Termination recommendations are provided in 3.3 HCSL Differential Output Terminations. Unused outputs should be left unconnected.
			Supply Voltage (1.8–3.3 V) for OUT2 and OUT3
25	VDDO2	Р	Leave VDDOx pins of unused output drivers unconnected. An alternate op- tion is to connect the VDDOx pin to a power supply and disable the output driver to minimize current consumption. Refer to 4. Power Supply Filtering Recommendations for bypass capacitor recommendations.
26	OUT4b	0	Output Clock
27	OUT4	0	100 MHz HCSL output. Termination recommendations are provided in 3.3 HCSL Differential Output Terminations. Unused outputs should be left unconnected.
			Supply Voltage (1.8–3.3 V) for OUT4 and OUT5
28	VDDO3	Р	Leave VDDOx pins of unused output drivers unconnected. An alternate op- tion is to connect the VDDOx pin to a power supply and disable the output driver to minimize current consumption. Refer to 4. Power Supply Filtering Recommendations for bypass capacitor recommendations.
29	OUT5b	0	Output Clock
30	OUT5	0	100 MHz HCSL output. Termination recommendations are provided in 3.3 HCSL Differential Output Terminations. Unused outputs should be left unconnected.

Pin Number	Pin Name	Pin Type	Function
			Output enable pin for OUT4.
31	OEb_OUT4	I	Low = output enabled
			High = output disabled
			Output enable pin for OUT5.
32	OEb_OUT5	I	Low = output enabled
			High = output disabled
			Supply Voltage (1.8–3.3 V) for OUT6
33	VDDO4	Р	Leave VDDOx pins of unused output drivers unconnected. An alternate op- tion is to connect the VDDOx pin to a power supply and disable the output driver to minimize current consumption. Refer to 4. Power Supply Filtering Recommendations for bypass capacitor recommendations.
34	OUT6b	0	Output Clock
35	OUT6	0	100 MHz HCSL output. Termination recommendations are provided in 3.3 HCSL Differential Output Terminations. Unused outputs should be left unconnected.
			Output enable pin for OUT6.
36	OEb_OUT6	I	Low = output enabled
			High = output disabled
			Output enable pin for OUT7.
37	OEb_OUT7	I	Low = output enabled
			High = output disabled
38	OUT7b	0	Output Clock
39	OUT7	0	100 MHz HCSL output. Termination recommendations are provided in 3.3 HCSL Differential Output Terminations. Unused outputs should be left unconnected.
			Supply Voltage (1.8–3.3 V) for OUT7
40	VDDO5	Ρ	Leave VDDOx pins of unused output drivers unconnected. An alternate op- tion is to connect the VDDOx pin to a power supply and disable the output driver to minimize current consumption. Refer to 4. Power Supply Filtering Recommendations for bypass capacitor recommendations.
			Ground Pad
41	GND PAD	Р	This pad provides electrical and thermal connection to ground and must be connected for proper operation.



Figure 6.2. 32-QFN



Pin Number	Pin Name	Pin Type	Function
1	VDD_DIG	Ρ	Voltage supply for digital functions. Connect to 1.8–3.3 V. Part of internal core VDD voltage. Must be connected to same voltage as VDDA and VDD_XTAL. Refer to 4. Power Supply Filtering Recommendations for bypass capacitor recommendations.
2	OEb_OUT0	I	Output enable pin for OUT0. Low = output enabled High = output disabled
3	OEb_OUT1	I	Output enable pin for OUT1. Low = output enabled High = output disabled
4	VDD_XTAL	Р	Voltage supply for crystal oscillator. Connect to 1.8–3.3 V. Part of internal core VDD voltage. Must be connected to same voltage as VDDA and VDD_DIG." Refer to 4. Power Supply Filtering Recommendations for bypass capacitor recommendations.
5	ХА		Refer to Section 5. Electrical Specifications for recommended crystal speci-
6	ХВ	0	fications.

Pin Number	Pin Name	Pin Type	Function
			Core Supply Voltage. Connect to 1.8–3.3 V.
7	VDDA	Р	See the Si5332-AM1/2/3 Family Reference Manual for power supply filter- ing recommendations.
	VDDA	Г	Must be connected to same voltage as VDD_DIG and VDD_XTAL.
			Refer to 4. Power Supply Filtering Recommendations for bypass capacitor recommendations.
8	LOS	0	The LOS status pin indicates whether the reference input has dropped be- low approximately 10 MHz. LOS is active low, open drain output and re- quires an external pull-up resistor of 1 to 10 k Ω for proper operation. If LOS is not required, this pin can be left unconnected.
			0 = reference input has dropped below approx. 10 MHz
			1 = reference input is present (>10 MHz)
9	GND	Р	Connect these pins to ground.
10	GND	Р	
11	OUT0b	0	Output Clock
12	OUTO	Ο	100 MHz HCSL output. Termination recommendations are provided in 3.3 HCSL Differential Output Terminations. Unused outputs should be left unconnected.
			Supply Voltage (1.8–3.3 V) for OUT0
12		_	See the Si5332-AM1/2/3 Family Reference Manual for power supply filter- ing recommendations.
13	VDDO0	Р	Leave VDDOx pins of unused output drivers unconnected. An alternate op- tion is to connect the VDDOx pin to a power supply and disable the output driver to minimize current consumption. Refer to 4. Power Supply Filtering Recommendations for bypass capacitor recommendations.
14	OUT1b	0	Output Clock
15	OUT1	0	100 MHz HCSL output. Termination recommendations are provided in 3.3 HCSL Differential Output Terminations. Unused outputs should be left unconnected.
			Supply Voltage (1.8–3.3 V) for OUT1
16	VDDO1	Р	Leave VDDOx pins of unused output drivers unconnected. An alternate op- tion is to connect the VDDOx pin to a power supply and disable the output driver to minimize current consumption. Refer to 4. Power Supply Filtering Recommendations for bypass capacitor recommendations.
			Output enable pin for OUT2.
17	OEb_OUT2	I	Low = output enabled
			High = output disabled
18	OUT2b	0	Output Clock
19	OUT2	0	100 MHz HCSL output. Termination recommendations are provided in 3.3 HCSL Differential Output Terminations. Unused outputs should be left unconnected.

Pin Number	Pin Name	Pin Type	Function
			Supply Voltage (1.8–3.3 V) for OUT2
20	VDDO2	Р	Leave VDDOx pins of unused output drivers unconnected. An alternate op- tion is to connect the VDDOx pin to a power supply and disable the output driver to minimize current consumption. Refer to 4. Power Supply Filtering Recommendations for bypass capacitor recommendations.
21	OUT3b	0	Output Clock
22	OUT3	0	100 MHz HCSL output. Termination recommendations are provided in 3.3 HCSL Differential Output Terminations. Unused outputs should be left unconnected.
			Supply Voltage (1.8–3.3 V) for OUT3
23	VDDO3	Р	Leave VDDOx pins of unused output drivers unconnected. An alternate op- tion is to connect the VDDOx pin to a power supply and disable the output driver to minimize current consumption. Refer to 4. Power Supply Filtering Recommendations for bypass capacitor recommendations.
			Output enable pin for OUT3.
24	OEb_OUT3	I	Low = output enabled
			High = output disabled
25	NC	_	
26	NC	—	Do not connect these pins to anything.
27	NC	—	
			Spread spectrum enable pin.
28	SSC_EN	I	Low = spread OFF
			High = spread ON (–0.5%)
			Impedance select pin for output drivers. IMP_SEL pin is sampled at power- up only.
29	IMP_SEL	I	Low = 100 Ω
			High = 85 Ω
30	NC		
31	NC	_	Do not connect these pins to anything.
32	NC		
			Ground Pad
33	GND PAD	Р	This pad provides electrical and thermal connection to ground and must be connected for proper operation.

7. Package Outline

7.1 Si52258A-D01AM 6x6 mm 40-QFN Package Diagram

The figure below illustrates the package details for the Si52258A-D01AM in 40-QFN. The table below lists the values for the dimensions shown in the illustration.



Figure 7.1. 40-Pin Quad Flat No-Lead (QFN)

Table 7.1.	Package	Dimensions
------------	---------	------------

Dimension	Min	Nom	Мах
A	0.80	0.85	0.90
A1	0.00	0.02	0.05
b	0.18	0.25	0.30
D		6.00 BSC	
D2	4.35	4.50	4.65
e	0.50 BSC		
E	6.00 BSC		
E2	4.35	4.50	4.65
L	0.30	0.40	0.50
aaa	_	—	0.15
bbb	—	—	0.15
CCC	—	—	0.08
ddd	—	—	0.10
eee			0.05

Dimension	Min	Nom	Мах	
Notes:				
1. All dimensions shown are in millimeters (mm) unless otherwise noted.				
2. Dimensioning and Tolerancing per ANSI Y14.5M-1994.				
3. This drawing conforms to the JEDEC Solid State Outline MO-220.				
4. Recommended card reflow p	rofile is per the JEDEC/IPC J-ST	D-020 specification for Small Body	Components.	

7.2 Si52254A-D01AM 5x5 mm 32-QFN Package Diagram

The figure below illustrates the package details for the Si52254A-D01AM 32-QFN option. The table below lists the values for the dimensions shown in the illustration.





Table 7.2.	Package	Dimensions
------------	---------	------------

Dimension	MIN	NOM	МАХ
A	0.80	0.85	0.90
A1	0.00	0.02	0.05
A3		0.20 REF	
b	0.18	0.25	0.30
D/E	4.90	5.00	5.10
D2/E2	3.40	3.50	3.60
e	0.50 BSC		
L	0.30	0.40	0.50
К	0.20		
R	0.09		0.14
aaa	0.15		
bbb	0.10		
ССС	0.10		

Dimension	MIN	NOM	MAX
ddd		0.05	
eee		0.08	
fff		0.10	

Notes:

1. All dimensions shown are in millimeters (mm) unless otherwise noted.

2. Dimensioning and Tolerancing per ANSI Y14.5M-1994.

3. This drawing conforms to the JEDEC Solid State Outline MO-220, Variation VKKD-4.

4. Recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.

8. PCB Land Pattern

8.1 Si52258A-D01AM 40-QFN Land Pattern







Dimension	mm
C1	5.90
C2	5.90
e	0.50 BSC
X1	0.30
Y1	0.85
X2	4.65
Y2	4.65

Dimension	mm
Notes: General	
1. All dimensions shown are in millimeters (mm) unless otherwise	e noted.
2. This Land Pattern Design is based on the IPC-7351 guidelines Solder Mask Design	
 All metal pads are to be non-solder mask defined (NSMD). Cle minimum, all the way around the pad. Stencil Design 	arance between the solder mask and the metal pad is to be 60 μn
1. A stainless steel, laser-cut and electro-polished stencil with trap 2. The stencil thickness should be 0.125 mm (5 mils).	pezoidal walls should be used to assure good solder paste release
3. The ratio of stencil aperture to land pad size can be 1:1 for all	perimeter pads.
4. A 3×3 array of 0.85 mm square openings on a 1.00 mm pitch c Card Assembly	an be used for the center ground pad.
1. A No-Clean, Type-3 solder paste is recommended.	

2. The recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.

8.2 Si52254A-D01AM 32-QFN Land Pattern

The figure below illustrates the PCB land pattern details for Si52254A-D01AM in 32-QFN package. The table below lists the values for the dimensions shown in the illustration.





Table 8.2.	PCB Land	Pattern	Dimensions
------------	----------	---------	------------

Dimension	mm
C1	4.90
C2	4.90
e	0.50 BSC
X1	0.30
Y1	0.85
X2	3.60
Y2	3.60

Dimension	mm	
Notes: General		
1. All dimensions shown are in millimeters (mm) unless otherwise	e noted.	
2. This Land Pattern Design is based on the IPC-7351 guidelines Solder Mask Design		
1. All metal pads are to be non-solder mask defined (NSMD). Clearance between the solder mask and the metal pad is to be 60 µ minimum, all the way around the pad. Stencil Design		
1. A stainless steel, laser-cut and electro-polished stencil with trapezoidal walls should be used to assure good solder paste rele 2. The stencil thickness should be 0.125 mm (5 mils).		
3. The ratio of stencil aperture to land pad size can be 1:1 for all perimeter pads.		
4. A 3×3 array of 0.85 mm square openings on a 1.00 mm pitch c Card Assembly	an be used for the center ground pad.	
1. A No-Clean, Type-3 solder paste is recommended.		

2. The recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.

9. Top Marking



Figure 9.1. Top Marking

Table 9.1. Top Marking Explanation

Line	Characters	Description	
1	Si52258 Si52254	Base part number	
2		A = Grade	
	AR01A	R = Product revision (reference ordering section for latest revision)	
	ARUTA	01 = Product identification, single input	
		A = Automotive temperature grade. Package (QFN)	
3	ТТТТТТ	Manufacturing trace code.	
4	YYWW	Year (YY) and work week (WW) of package assembly	

10. Revision History

Revision 1.0

January, 2021

- Updated Table 5.4 Differential Clock Output Specifications on page 9.
- Updated Table 6.1 Si52258A-D01AM Pin Descriptions (40-QFN) on page 15.
- Removed "Default low" from hardware input pin function descriptions.
- Updated Table 6.2 Si5224A-D01AM Pin Descriptions, (32-QFN) on page 18.
 - Removed "Default low" from hardware input pin function descriptions.
- Updated 9. Top Marking.
- Updated Typ/Max performance specs in Table 5.6 PCI-Express Clock Outputs (100 MHz HCSL) on page 11.

Revision 0.7

September, 2019

· Initial release.

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